

UTC UNISONIC TECHNOLOGIES CO., LTD

BAV199

Preliminary

DIODE

DUAL SURFACE MOUNT LOW LEAKAGE DIODE

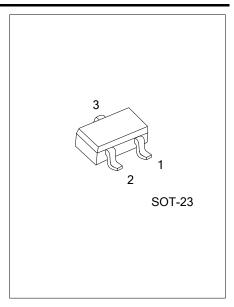
DESCRIPTION

The UTC BAV199 is a dual surface mount diode providing the designers with extremely low leakage current.

The UTC BAV199 is suitable for automatic insertion

FEATURES

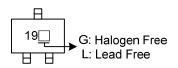
* Extremely Low Leakage Current



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing	
Lead Free	Halogen Free	гаскауе	1	2	3	Facking	
BAV199L-AE3-R	BAV199G-AE3-R	SOT-23	K1	A2	A1K2	Tape Reel	
Note: Pin Assignment: A: Anode K: Cathode							
BAV199L-AE3-R (1) Packing Type (2) Package Type (3) Lead Free		1) R: Tape Reel 2) AE3 : SOT-23 3) Halogen Free		Free			

MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Peak Repetitive Reverse Voltage		V _{RRM}	85	V	
Working Peak Reverse Voltage		V _{RWM}	85	V	
DC Blocking Voltage		V _R	85	V	
RMS Reverse Voltage		V _{R(RMS)}	60	V	
Forward Continuous Current	Single diode		160		
	Double diode	I _{FM}	140	— mA	
Repetitive Peak Forward Current		I _{FRM}	500	mA	
Non-Repetitive Peak Forward Surge Current	@ t = 1.0µs		4.0		
	@ t = 1.0ms	I _{FSM}	1.0	А	
	@ t = 1.0s	1	0.5		
Power Dissipation (Note 2)		PD	250	mW	
Junction Temperature		TJ	-65~+150	°C	
Storage Temperature		T _{STG}	-65~+150	°C	

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Part mounted on FR-4 PC board with recommended pad layout

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Thermal Resistance Junction to Ambient Air (Note 2)	θ _{JA}	500	°C/W	

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R = 100μA	85			V	
Forward Voltage (Note 1)	V _F	I _F = 1.0mA			0.90		
		I _F = 10mA			1.0	V	
		I _F = 50mA			1.1		
		I _F = 150mA			1.25		
Leakage Current (Note 1)		V _R = 75V			5.0	n A	
		V _R = 75V, T _J = 150°C			80	nA	
Total Capacitance	CT	V _R = 0, f = 1.0MHz		2		pF	
Reverse Recovery Time	t _{rr}	$I_F = I_R = 10$ mA, $I_{rr} = 0.1 \times I_R$, R _L = 100Ω			3.0	μs	

Note: 1. Short duration test pulse to minimize self-heating effect.

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